MAGNETIC PHASE TRANSITIONS OF T'-PHASE Gd₂CuO₄ SINGLE CRYSTAL

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ABSTRACT

MAGNETIC PHASE TRANSITIONS OF T`-PHASE Gd_CuO_4 SINGLE CRYSTAL. The magnetic properties of T'-phase Gd_2CuO_4 Single crystal grown by the Traveling Solvent Floating Zone (TSFZ) method have been investigated by means of ac-magnetic susceptibility and dc-magnetization measurements. The result of these studies revealed an anomaly in the temperature dependent magnetization at temperature of T = 6.5, 290 and 20 K, associated respectively with the long-range antiferroniagtietic ordering of the Gd and Cu ions and Cu-spin reorientation transitions. The complex magnetic structure of this compound shown by the weak ferromagnetic behavior below the copper ordering temperature ($T_N(Cu) = 290 \text{ K}$) is induced by an effective field due to exchange interactions between the ordered copper moments and the rare-earth ions. These results, together with the previous neutron diffraction measurement, establishes the existence of ferromagnetic Gd layers in the ab-plane which are stacked antiferromagnetically along c-direction, indicating a quasi-two dimensional antiferromagnetic nature of Gd_2CuO_4 .

Key words: Gd₂CuO₄ single crystal, Traveling Solvent Floating Zone (TSFZ) method, magnetic properties.

ABSTRAK

TRANSISI FASE MAGNETIK PADA KRISTAL TUNGGAL FASE-T'Gd₂CuO₄. Telah ditelaah dalam studi ini sifat-sifat magnetik dari kristal tunggal fase-T'Gd₂CuO₄ melalui pengukuran suseptibilitas AC-magnetik don magnetisasi DC. Hasil-hasil dari studi ini menunjukkan sebuah anomali pada kebergantungan temperatur dari magnetisasi pada suhu 6,5 , 290 dan 20 K, masing-masing diasosiasikan dengan *ordering* antiferromagnetik berjangkauan panjang dari ion-ion Gd dan Cu dan transisi reorientasi spin dari ion-ion Cu. Struktur magnetik yang kompleks dari sistem ini seperti diperlihatkan oleh kelakuan ferromagnetik lemah pada temperatur di bawah suhu *ordering* Cu(T_N (Cu) = 290 K), disebabkan oleh sebuah medan efektiv dari interaksi tukar antara momen-momen magnetik Cu yang terorder dan ion-ion tanah jarang. Hasil-hasil eksperimen ini bersama-sama dengan hasil pengukuran defraksi neutron terdahulu, menkonfirmasi kehadiran dari lapisan ferromagnetik Gd pada bidang-ab yang tersusun secara antiferromagnetik sepanjang arah-c, mengindikasikan sifat quasi-dua dimensi dari sistem Gd_2CuO_4 .

Kata kunci: Kristal tunggal Gd, CuO₄, metoda Traveling Solvent Floating Zone (TSFZ), sifat-sifat magnet.

INTRODUCTION

The magnetic properties of $R_2\text{CuO}_4$ (R = Pr, Nd, Sm, Eu, Gd) crystallize in the tetragonal T'-phase structure of Nd_2CuO_4 [1] with the Cu sublattice presents three-dimensional antiferromagnetic (AF) order below $T_N = 250-290\,\text{K}$ [2]. Among them, the compound Gd_2CuO_4 occupies a unique place in this family for some reasons: first, although it is easily doped with Ce or Th, it does not become superconducting as the other members; second, the square array of oxygen ions surrounding the Cu atoms is rotated around the c-axis, leading to a

reduced orthorhombic symmetry (space group Acam) [3,4]. As the result, the AF order is not perfect in this case and weak ferromagnetism (WF) appears due to canting of the Cu moments in the CuO₂ planes [5-7]. The origin of this canting has been attributed to an antisymmetric exchange interaction of Dzyaloshinskii-Moriya (DM) type [8] allowed in this case by the orthorhombic distortion.

We present in this study the magnetic properties of a Gd₂CuO₄ single crystal grown by means of the

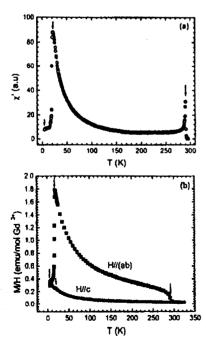
Traveling Solvent Floating Zone (TSFZ) method. The magnetic properties have been explored by ac-magnetic susceptibility and dc-magnetization measurements. In ref. [6] it has been suggested that the in-plane anisotropy Gd_2CuO_4 compound was relatively small. For that reason we ignore the in-plane anisotropy in our measurement. The detailed study about the in-plane magnetization anisotropy has been reported in ref. [9].

EXPERIMENTS

The T'-phase Gd,CuO₄ single crystal was grown by the Traveling Solvent Floating Zone (TSFZ) method using a four-mirror furnace from Crystal system, Inc. The quality of the as-grown crystal was examined by X-ray LAUE diffraction pattern using DIFFRACTIS 582 of ENPAF NONIUS, and Electron Probe Micro Analysis (EPMA) using JEOL JXA-8621. The AC-susceptibility measurement has been carried out in a homemade system using a mutual inductance technique. With this system, the measurements can be performed in the temperature range between 4.2 and 300 K at an appropriate cooling or heating rate by manipulating the vacuum in the heat-exchange space of the measurement insert. The dc-magnetization measurements were measured by a commercial Quantum Design (SQUID) MPMS 5 magnetometer. Both of these measurements were performed at the Van der Waals-Zeeman Institute, University of Amsterdam.

RESULTS AND DISCUSSION

The results of the temperature dependent AC-susceptibility and dc-magnetization measurements are given in Fig. 1. The development of anisotropy is readily apparent from this figure. The AC-susceptibility



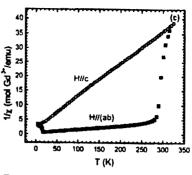
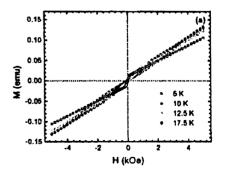


Fig. 1(a). Temperature dependent AC-magnetic susceptibility, (b). dc-magnetization measurements and (c). inverse molar susceptibility for field direction in the plane (χ_{ab}^{-1}) and along the c-axis (χ_{ab}^{-1}) .

and dc-magnetization measurement for field parallel to the plane (H//ab; χ_{ab}) show an anomaly at T = 6.5, 20 and 290 K, in good agreement with the previous report [5,10-13]. The dc-magnetization measurement for field parallel perpendicular to the plane $(H//c; \chi_c)$ on the other hand, shows the anomaly at 6.5 and 20 K only. The Currie-Weiss bellavior is shown by $1/\chi_c$, curve for T > 20K as depicted in Fig. 1(c). The effective magnetic moment determined from this plot is $\mu_{eff} = 8.37 \ \mu_{B}/\text{Gd}^{3+}$ atom and paramagnetic Curie temperature $\theta = 15.51$ K. These values are to be compared with previous reports [2,5] and close to its free ion value of μ_{eff} = $7.94 \,\mu_n/Gd^{3+}[14]$. We note that for H parallel to the planes and temperature less than ~ 200 K, $\mu_{eff} = 25.3 \ \mu_{B}/\text{Cd}^{3+}$ atom and $\theta = 27.37$ K; these values are bigger than the previous report by Thompson ct.al. [5]. The reasons for the lower and higher anomalies are associated with the antiferromagnetic ordering of Gd and Cu ions. At $T_{N}(Cu)$ = 290 K, the Cu magnetic moments order to a La, NiO₄-like antiferromagnetic (AF) structure with spin direction of Cu ions parallel to [110]. At $T_N(Gd) = 6.5 \text{ K}$ the Gadolinium ions order antiferromagnetically with special configuration, namely the two centrosymmetrically related Gd atoms in the primitive unit cell are oppositely oriented. The explanation for the mid temperature anomaly T = 20 K will be presented in the following paragraph.

The plots of field dependent magnetization at certain temperature, $M(H)_T$ for H//(a,b) is shown in Fig. 2 and 3 associated respectively for temperature range below and above $T_c = 20$ K. Two important features



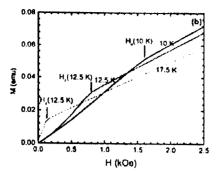
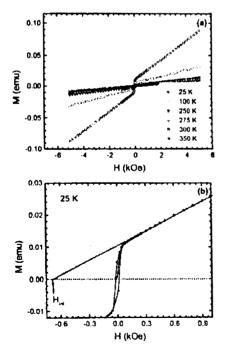


Fig. 2(a). Isothermal magnetic hysteresis loop of a Gd_2CuO_4 single crystal measured at various temperature below $T_c=20 \text{ K}$. (b). The M(H) curves in the temperature range of $T_{\infty}(Gd) < T < T_{c}$, showing two linear parts of the curves with different slope, intersect each other at H_c See text for discussion.

observed which indicate the presence of a phase transition: (1) The small but significant hysteresis at $H\approx 0$, which is present at all temperatures below $T_{N}(Cu)$ and gradually disappear below $T_c = 20$ K. This behavior is clearly seen in Fig. 3(b) for T=25 K. The form of the M(H) curves in the temperature range of $T_N(Gd) < T < T_C$ have two almost linear parts with different slopes, intersect each other at H_c as depicted by arrowheads in Fig. 2(b). From this figure one can see that the value of Hdecreases with increasing temperature. Further, the lower part of the M(H) curves $(H < H_c)$ passes through the origin when extrapolated to H=0, indicate a pure AF phase is stable when $H < H_c$. These results clearly show that the WF phase only exists in Gd,CuO4 in zero-field for $T > T_c$, although below T_c it can be induced by a magnetic field applied in the ab-plane. We concluded that a WF-AF phase transition does occur in zero-field at T=20 K. An important characteristic of the WF phase is the value of the internal field H_{int} , which induces the weak



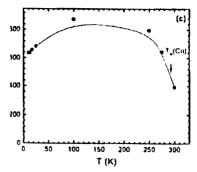


Fig. 3(a) Isothermal magnetic hysteresis loop of a $Gd_{\lambda}CuO_{\lambda}$ single crystal measured at various temperature above T_{c} (b). The schematic picture showing the determination of internal field H_{int} , for T=25 K. (c). Temperature dependent internal field H_{int} (7). See text for discussions.

ferromagnetic moment in the ab-plane. We determined the $H_{\rm int}$ values by extrapolating the linear high-field part of the curves (according to linearity criterion of R=1) to M=0 as illustrated in Fig. 3(b) for T=25 K. The temperature dependent internal field $H_{\rm int}(T)$ is shown in Fig. 3(c).

Having gone through the above analysis, we are attempting now to discuss the complex magnetic structure of this Gd, CuO₄ compound. In the temperature region of $T < T < T_N(Cu)$, the Cu-spins have long-range antiferromagnetic order with a significant weak ferromagnetic moment parallel to the ab-planes, arises from polarization of the paramagnetic Gd sublattice by exchange interaction with the ordered Cu subsystem. The weak ferromagnetism results from a strong intraplanar spin-spin interaction. At $T = T_c$ a phase transition to a purely antiferromagnetic state with weak ferromagnetism behavior takes place. These weak ferromagnetic moments in the temperature region of $T_{N}(Gd) < T < T_{A}$ are easily induced by relatively weak magnetic fields applied perpendicular to the c-axis. Such behavior suggests that a weak ferromagnetic moment exists independently in each CuO, plane and that the phase transition at T_c is associated with the appearance of substantial antiferromagnetic correlation between weak ferromagnetic moments of adjacent CuO, planes. The role of the

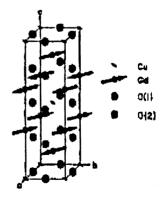


Fig. 4 The proposed magnetic structure of Gd_2CuO_4 in the antiferromagnetic phase at $T < T_{\kappa}(Gd) = 6.5$ K

relatively weak interplanar interaction is to produce some correlation between the orientation of the weak ferromagnetic moments in neighboring CuO₂ planes. The crystal structure of Gd₂CuO₄ deduced from neutron diffraction measurement [11] and in conformity with the above analysis is shown in Fig. 4. This figure establishing the existence of ferromagnetic Gd layers in theab-plane which are stacked antiferromagnetically along c-direction, thus indicating a quasi two dimensional antiferromagnetic nature of Gd₂CuO₄ system.

SUMMARY

We have presented in this study the magnetic properties Gd,CuO₄ single crystal grown by the TSFZ method. Temperature dependent magnetization shows a clear anomaly at T = 6.5, 290, and 20 K, associated respectively with the long-range antiferromagnetic ordering of the Cd and Cu ions and Cu-spin reorientation transitions. In addition, a weak ferromagnetic behavior induced by an effective field due to exchange interactions between the ordered copper moments and the rare-earth ions was developed below the copper ordering temperature $(T_N(Cu) = 290 \text{ K})$. These results establishes the existence of ferromagnetic Gd layers in the ab-plane which are stacked antiferromagnetically along c-direction, indicating a quasi-two dimensional antiferromagnetic nature of Gd₂CuO₄ in concurrent with neutron diffraction results.

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REFERENCES

- [1]. HK. MÛLLER~BUSCHBAUM and W. WOLLSCHLÄGER, Z. Anorg. Allg. Chem. 414 (1975) 76.
- [2]. R. SAEZ PUCHE, M. NORTON, and W.S. GLAUSINGER, Mater. Res. Bull. 17 (1982) 1523; R. SAEZ PUCLIC, M. NORTON, T.R. WHITE and W.S. GLAUSINGER, J. Solid State Chem. 50 (1983) 281.
- [3]. M. BRADEN, W. PAULUS, A. CAUSSON, P. VIGOUREUX, G. HEGER, A. GAUKASSOV, P. BOURGES and D. PETITGRAND, *Europhys. Lett.* **25** (1994) 625

- [4]. H.M. LUO, Y.Y. HSU, B.N. LIN, Y.P. CHI, T.J. LEE and H.C. KU, *Phys. Rev. B* **60** (13) (1999) 119.
- [5]. J.D. THOMPSON, S.W. CHEONG, S.E. BROWN, Z. FISK, S.B. OSEROFF, M. TOVAR, D.C. VIER and S. SCHULTZ, *Phys. Rev. B* 39 (1989) 6660
- [6]. S.B. OSEROFF, D. RAO, F. WRIGHT, D.C. VIER, S. SCHULTZ, J.D. THOMPSON, Z. FISK, S.W. CHEONG, M.F. HUNDLEY and M. TOVAR, *Phys. Rev. B* 41 (1990) 1934.
- [7]. M. TOVAR, X. OBRADORS, F. PEREZ, S.B. OSEROFF, R.J. DURO, J. RIVAS, D. CHATEIGNER, P. BORDET, and J. CHENAVAS, *Phys. Rev. B* 45 (1992) 4729.
- [8]. I.E. DZYALOSHINSKII, J. Chem. Phys. Solids 4 (1958) 241; T. MORIYA, in Magnetism, Edited by G.T. RADO and H. SUHL, Academic Press, New York, Vol. 1 (1966) 85.
- [9]. A. BUTERA, M. TOVAR, S.B. OSEROFF, Z. FISK, Phys. Rev. B 52 (13) (1995) 444.
- [10]. CHATTOPADHYAY, P.J. BROWN, A.A. STEPANOV, P. WYDER, J. VOIRON, A.I. ZVYAGIN, S.N. BARILO, D.J. ZHIGUNOV and I. ZOBKALO, Phys. Rev. B 44 (1991) 9486.
- [11]. A.A. STEPANOV, P. WYDER, T. CHATTOPADBYAY, P.J. BROWN, G. FILLION, I.M. VITEBSKY, A. DEVILLE, B. GAILLARD, S.N. BARILO and D.I. ZHIGUNOV, *Phys. Rev. B* 48 (12) (1993) 979.
- [12]. P.W. KLAMUT, Phys. Rev. B 50 (13) (1994).
- [13]. P.W. KLAMUT, K. ROGACKI, A. SIKORA and B. DABROWSKI, J. Appl. Phys. 84 (1998) 5129.
- [14]. R.S. TEBBLE, D.J. CRAIK, Magnetic Materials, John Wiley and Sons, (1969) 184.